



BS170P

60V N-CHANNEL ENHANCEMENT MODE VERTICAL DMOSFET

Features

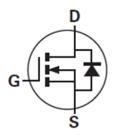
- BV_{DSS} > 60V
- $R_{DS(ON)} \le 5\Omega$ @ $V_{GS} = 10V$
- I_D = 270mA Maximum Continuous Drain Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

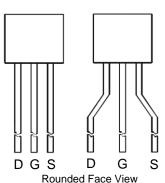
- Case: E-Line (TO-92 Compatible)
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.159 grams (Approximate)

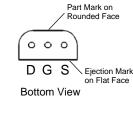












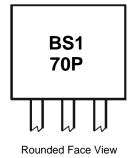
Ordering Information (Note 4)

Product	Marking	Package	Leads	Quantity
BS170P	BS170P	E-Line	Straight	4,000 Loose in a Box
BS170PSTZ	BS170P	E-Line	Joggled	2,000 Taped per Ammo Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



BS170P = Product Type Marking Code



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V
Gate-Source Voltage	V_{GSS}	±20	V
Continuous Drain Current	I _D	270	mA
Pulsed Drain Current	I _{DM}	3	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	625	mW
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

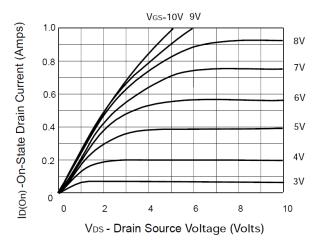
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$I_D = 100 \mu A, V_{GS} = 0 V$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	0.5	μΑ	$V_{DS} = 25V, V_{GS} = 0V$
Gate-Body Leakage	I _{GSS}	_	_	±10	nA	$V_{GS} = \pm 15V, V_{DS} = 0V$
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(th)}	0.8	_	3.0	V	$I_D = 1 \text{mA}, V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 5)	R _{DS(ON)}	_	_	5	Ω	$V_{GS} = 10V, I_D = 200mA$
Forward Transconductance (Notes 5 & 7)	g _{fs}	_	200	_	mS	$V_{DS} = 10V, I_D = 200mA$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{iss}	_	60	_	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz
Turn-On Delay Time (Note 6)	t _{D(ON)}	_	_	10	20	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Turn-Off Delay Time (Note 6)	t _{D(OFF)}	_	_	10	ns	$V_{DD} = 15V, I_D = 600mA$

Notes:

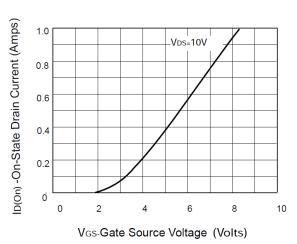
- 5. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.
 6. Switching characteristics are independent of operating junction temperature. Switching times are measured with a 50Ω source impedance and <5ns rise time on a pulse generator.</p>
 7. For design aid only, not subject to production testing.



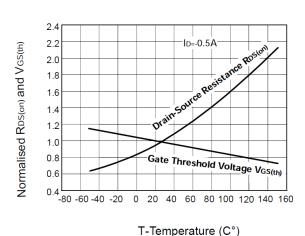
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



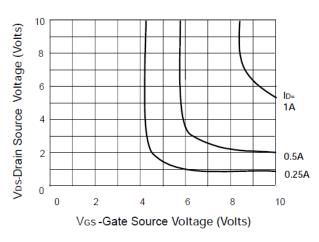
Saturation Characteristics



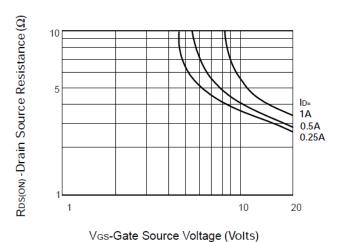
Transfer Characteristics



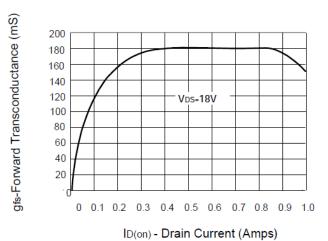
Normalised RDS(on) and VGS(th) vs Temperature



Voltage Saturation Characteristics



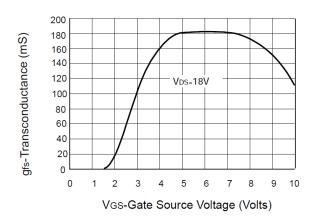
On-resistance vs gate-source voltage



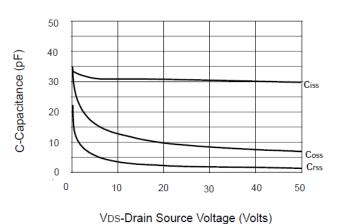
Transconductance v drain current



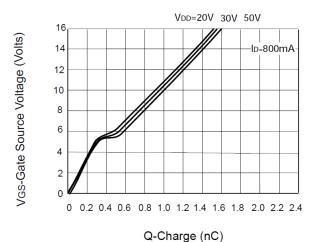
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) (Cont.)



Transconductance v gate-source voltage



Capacitance v drain-source voltage

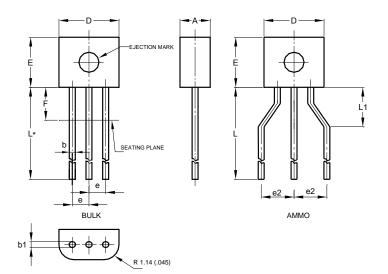


Gate charge v gate-source voltage



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



E-Line					
Dim	Min	Max	Тур		
Α	2.16	2.41	_		
b	0.41	0.495	-		
b1	0.41	0.495	-		
D	4.37	4.77	-		
Е	3.61	4.01	-		
е	_	_	1.27		
e2	_	_	2.54		
F	_	2.50	_		
L	13.00	13.97	-		
L1	2.50	3.50	-		
All Dimensions in mm					



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